



Product Overview

NSI1200 is a high-performance isolated amplifier with output separated from input based on the NOVOSENSE capacitive isolation technology. The device has a linear differential input signal range of $\pm 250\text{mV}$ ($\pm 320\text{mV}$ full-scale). The differential input is ideally suited to shunt resistor-based current sensing in high voltage applications where isolation is required.

The device has a fixed gain of 8 and provides a differential analog output.

The low offset and gain drift ensure the accuracy over the entire temperature range. High common-mode transient immunity ensures that the device is able to provide accurate and reliable measurements even in the presence of high-power switching such as in motor control applications.

The fail-safe functions including input common-mode overvoltage detection and missing VDD1 detection simplify system-level design and diagnostics.

Key Features

- Up to $5000V_{\text{rms}}$ Insulation voltage
- $\pm 250\text{mV}$ linear Input Voltage Range
- Fixed Gain: 8
- Low Offset Error and Drift: $\pm 0.5\text{mV}$ (Max), $-4 \sim 4\mu\text{V}/^\circ\text{C}$ (Max)
- Low Gain Error and Drift: $\pm 0.3\%$ (Max), $\pm 50\text{ppm}/^\circ\text{C}$ (Max)
- Low Nonlinearity and Drift: $\pm 0.03\%$ (Max), $\pm 1\text{ppm}/^\circ\text{C}$ (Typ)
- SNR: 86dB (Typ, BW=10kHz), 72dB (Typ, BW=100kHz)
- Bandwidth: 100kHz (Typ)
- High CMTI: $150\text{kV}/\mu\text{s}$ (Typ)
- System-Level Diagnostic Features:
 - VDD1 monitoring
 - Input common-mode overvoltage detection

- Input common-mode overvoltage detection
- Operation Temperature: $-40^\circ\text{C} \sim 125^\circ\text{C}$
- RoHS-Compliant Packages:
 - SOP8(300mil)
 - DUB8

Safety Regulatory Approvals

- UL recognition: up to $5000V_{\text{rms}}$ for 1 minute per UL1577
- CQC certification per GB4943.1-2011
- CSA component notice 5A approval IEC60950-1 standard
- DIN VDE V 0884-11:2017-01

Applications

- Shunt current monitoring
- AC motor controls
- Power and solar inverters
- Uninterruptible Power Suppliers
- Automotive onboard chargers

Device Information

| Part Number | Package | Body Size |
|---------------|--------------|-----------------|
| NSI1200-DSWVR | SOP8(300mil) | 5.85mm × 7.50mm |
| NSI1200-DDBR | DUB8 | 9.27mm × 6.20mm |

Functional Block Diagrams

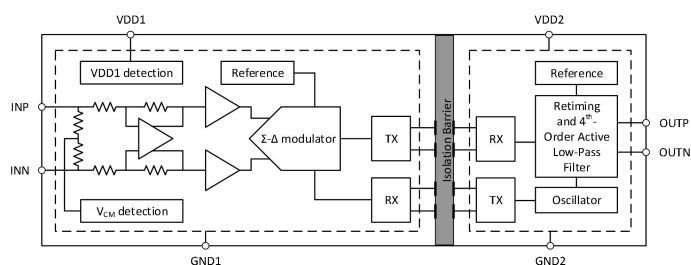


Figure 1. NSI1200 Block Diagram

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1. Pin Configuration and Functions

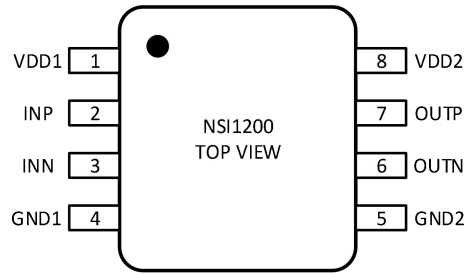


Figure 1.1 NSi1200 Package

Table 1.1 NSi1200 Pin Configuration and Description

| <i>NSi1200 PIN NO.</i> | <i>SYMBOL</i> | <i>FUNCTION</i> |
|------------------------|---------------|-----------------------------------------------------------|
| 1 | VDD1 | Power supply for isolator side 1(3.0V to 5.5V) |
| 2 | INP | Positive analog input (±250mV recommended for NSi1200) |
| 3 | INN | Negative analog input |
| 4 | GND1 | Ground 1, the ground reference for Isolator Side 1 |
| 5 | GND2 | Ground 2, the ground reference for Isolator Side 2 |
| 6 | OUTN | Negative output |
| 7 | OUP | Positive output |
| 8 | VDD2 | Power supply for isolator side 2 (3.0V to 5.5V) |

2. Absolute Maximum Ratings

| Parameters | Symbol | Min | Typ | Max | Unit |
|-------------------------------|--------------------|----------|-----|----------|------|
| Power Supply Voltage | VDD1, VDD2 | -0.3 | | 6.5 | V |
| Input Voltage | INP, INN | GND1-6 | | VDD1+0.5 | V |
| Output Voltage | OUTP, OUTN | GND2-0.5 | | VDD2+0.5 | V |
| Output current per Output Pin | I _o | -10 | | 10 | mA |
| Operating Temperature | T _{OPR} | -40 | | 125 | °C |
| Junction Temperature | T _J | -40 | | 150 | °C |
| Storage Temperature | T _{STG} | -55 | | 150 | °C |
| Electrostatic discharge | HBM ⁽¹⁾ | ±2000 | | | V |
| | CDM ⁽²⁾ | ±1000 | | | V |

(1) Human body model (HBM), per AEC-Q100-002-RevD

(2) Charged device model (CDM), per AEC-Q100-011-RevB

3. Recommended Operating Conditions

| Parameters | Symbol | Min | Typ | Max | Unit |
|---------------------------------------------------|-----------------------|-------|------|-----|------|
| Side1 Power Supply | VDD1 | 3.0 | 5.0 | 5.5 | V |
| Side2 Power Supply | VDD2 | 3.0 | 3.3 | 5.5 | V |
| Differential input voltage before clipping output | V _{Clipping} | | ±320 | | mV |
| Linear differential input full scale voltage | V _{FSR} | -250 | | 250 | mV |
| Operating common-mode input voltage | V _{CM} | -0.16 | | 0.8 | V |
| Operating Ambient Temperature | T _A | -40 | | 125 | °C |

4. Thermal Information

| Parameters | Symbol | DUB8 | SOP8(300mil) | Unit |
|----------------------------------------------|-----------------------|------|--------------|------|
| Junction-to-ambient thermal resistance | R _{θJA} | 76 | 86 | °C/W |
| Junction-to-case (top) thermal resistance | R _{θJC(top)} | 58 | 28 | °C/W |
| Junction-to-board thermal resistance | R _{θJB} | 40 | 42 | °C/W |
| Junction-to-top characterization parameter | ψ _{JT} | 27 | 4 | °C/W |
| Junction-to-board characterization parameter | ψ _{JB} | 38 | 42 | °C/W |

5. Specifications

5.1. Electrical Characteristics

(VDD1 = 3.0V ~ 5.5V, VDD2 = 3.0V ~ 5.5V, INP = -250mV to +250mV, and INN = GND1 = 0V, T_A = -40°C to 125°C. Unless otherwise noted, Typical values are at VDD1 = 5V, VDD2 = 3.3V, T_A = 25°C)

| Parameters | Symbol | Min | Typ | Max | Unit | Comments |
|-----------------------------------------------|-----------------------|--------|--------|-------|-------------------|--------------------------------------------------------------------------------------------------|
| Power Supply | | | | | | |
| Side1 Supply Voltage | VDD1 | 3.0 | 5.0 | 5.5 | V | |
| Side2 Supply Voltage | VDD2 | 3.0 | 3.3 | 5.5 | V | |
| Side1 Supply Current | IDD1 | | 11.4 | 15 | mA | |
| Side2 Supply Current | IDD2 | | 6.3 | 8 | mA | |
| VDD1 undervoltage detection threshold voltage | VDD1 _{UV} | 1.8 | 2.3 | 2.7 | V | VDD1 falling |
| Analog Input | | | | | | |
| Common-mode overvoltage detection level | V _{CMov} | 0.9 | | | V | Detection level has a typical hysteresis of 96 mV |
| Input offset voltage | V _{OS} | -0.5 | ±0.01 | 0.5 | mV | INP = INN = GND1 |
| Input offset drift | TCV _{OS} | -4 | 1 | 4 | μV/°C | |
| Common-mode rejection ratio | CMRR _{dc} | | -80 | | dB | INP = INN, f _{IN} = 0 Hz, V _{CM min} ≤ V _{IN} ≤ V _{CM max} |
| | CMRR _{ac} | | -106 | | dB | INP = INN, f _{IN} = 10 kHz, V _{CM min} ≤ V _{IN} ≤ V _{CM max} |
| Single-ended input resistance | R _{IN} | | 19 | | kΩ | INN = GND1 |
| Differential input resistance | R _{IND} | | 22 | | kΩ | |
| Input bias current | I _{IB} | -20 | -18 | -15 | μA | INP = INN = GND1, I _{IB} = (I _{IBP} + I _{IBN}) / 2 |
| Input bias current drift | TCI _{IB} | | ±1.8 | | nA/°C | |
| Analog Output | | | | | | |
| Nominal Gain | | | 8 | | V/V | |
| Gain error | E _G | -0.3% | ±0.05% | 0.3% | | |
| Gain error thermal drift | TCE _G | -50 | ±15 | 50 | ppm/°C | |
| Nonlinearity | | -0.03% | ±0.01% | 0.03% | | |
| Nonlinearity drift | | | ±1 | | ppm/°C | |
| Total harmonic distortion | THD | | -80 | | dB | V _{IN} = 0.5V, f _{IN} = 10kHz, BW = 100kHz |
| Output noise | | | 180 | | μV _{RMS} | INP = INN = GND1, BW = 100kHz |
| Signal to noise ratio | SNR | 79 | 86 | | dB | V _{IN} = 0.5V, f _{IN} = 1kHz, BW = 10kHz |
| | | | 72 | | dB | V _{IN} = 0.5V, f _{IN} = 10kHz, BW = 100kHz |
| Common-mode output voltage | V _{CMout} | 1.36 | 1.4 | 1.46 | V | |
| Failsafe differential output voltage | V _{FAILSAFE} | | -2.53 | -2.44 | V | V _{CM} > V _{CMov} , or VDD1 missing |

| Parameters | Symbol | Min | Typ | Max | Unit | Comments |
|-------------------------------------------------|--------------------|-----|-------|-----|-------|--------------------------------------------------------------------------|
| Output bandwidth | BW | 60 | 100 | | kHz | |
| Power supply rejection ratio ⁽¹⁾ | PSRR _{dc} | | -104 | | dB | PSRR vs VDD1, at DC |
| | PSRR _{ac} | | -102 | | dB | PSRR vs VDD1, 100mV and 10kHz ripple |
| | PSRR _{dc} | | -90 | | dB | PSRR vs VDD2, at DC |
| | PSRR _{ac} | | -85 | | dB | PSRR vs VDD2, 100mV and 10kHz ripple |
| Output resistance | R _{OUT} | | < 0.2 | | Ω | |
| Common-mode transient immunity | CMTI | 100 | 150 | | kV/μs | Common-mode transient immunity |
| Timing | | | | | | |
| Rising time of OUTP, OUTN | t _r | | 3.6 | | μs | |
| Falling time of OUTP, OUTN | t _f | | 3.6 | | μs | |
| INP, INN to OUTP, OUTN signal delay (50% - 50%) | t _{PD} | | 3.5 | 4 | μs | |
| Analog setting time | t _{AS} | | 0.5 | | ms | VDD1 step to 3.0 V with VDD2 ≥ 3.0 V, to OUTP, OUTN valid, 0.1% settling |

(1) Input referred.

5.2. Typical Performance Characteristics

Unless otherwise noted, test at VDD1 = 5V, VDD2 = 3.3V, Vin = -250mV to 250mV.

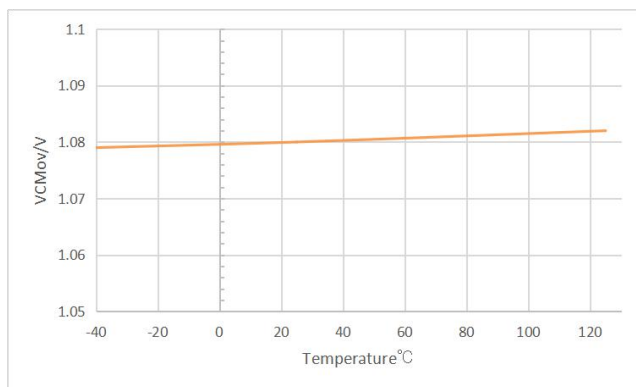


Figure 5.1 Common-Mode Overtolerance Detection Level vs Temperature

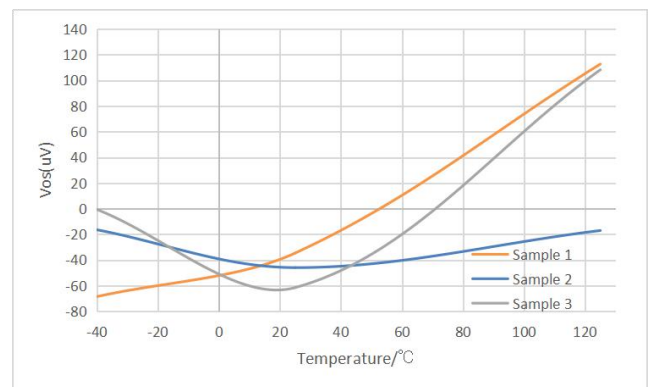


Figure 5.2 Input Offset Voltage vs Temperature (NSI1200)

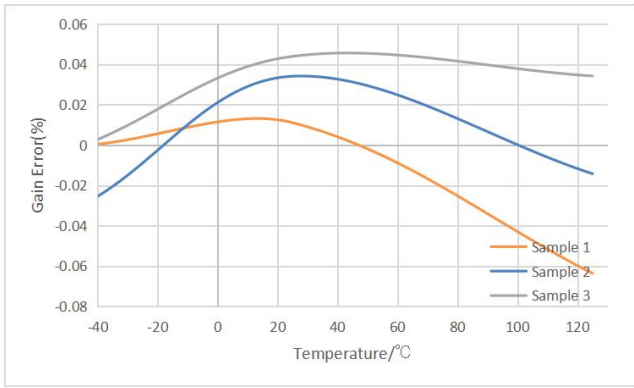


Figure 5.3 Gain Error vs Temperature

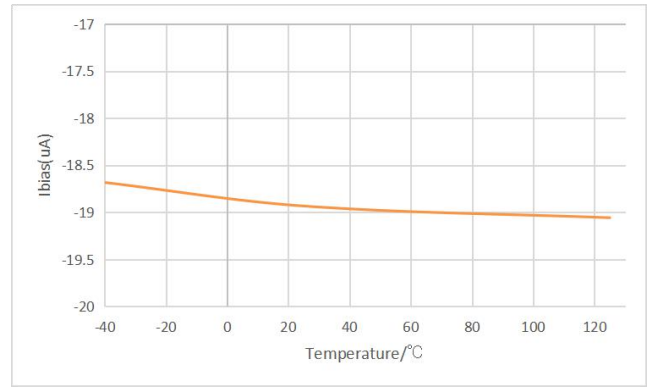


Figure 5.7 Input Bias Current vs Temperature

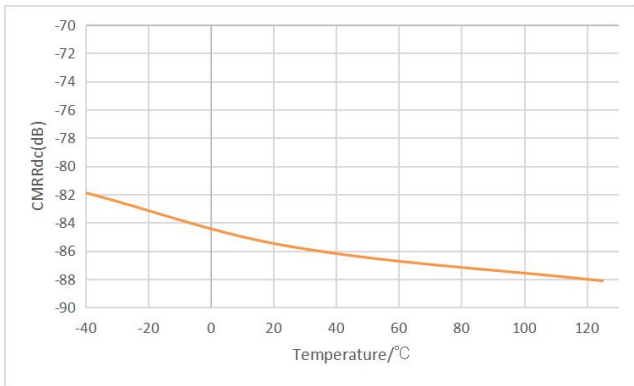


Figure 5.4 Common-Mode Rejection Ratio vs Temperature

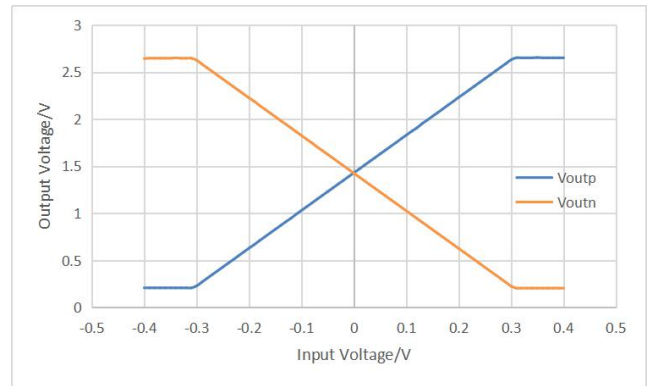


Figure 5.8 Output Voltage vs Input Voltage

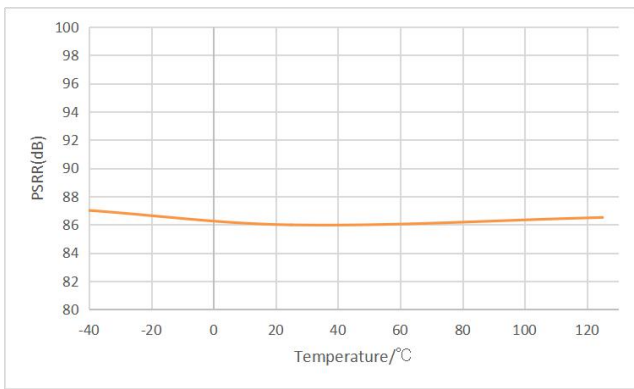


Figure 5.5 SNR vs Temperature

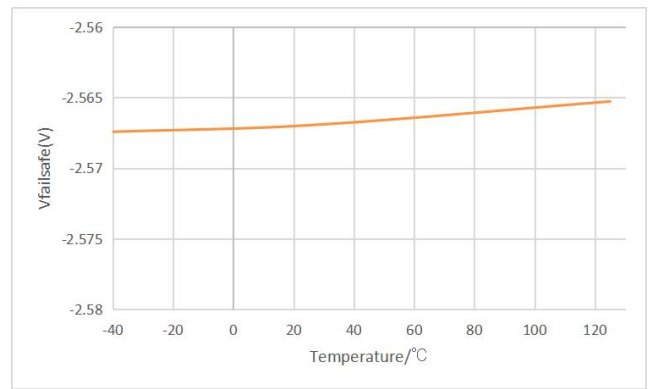


Figure 5.9 Fail-Safe Output Voltage vs Temperature

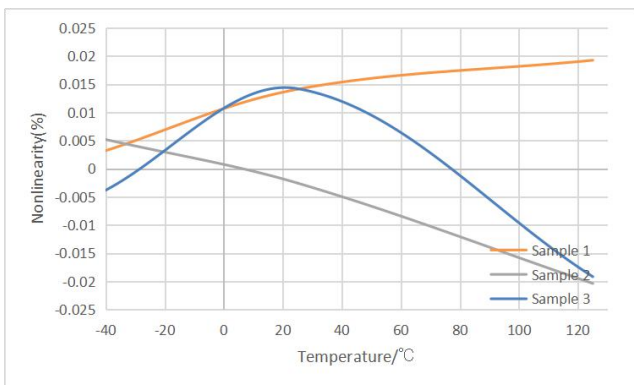


Figure 5.6 Nonlinearity vs Temperature

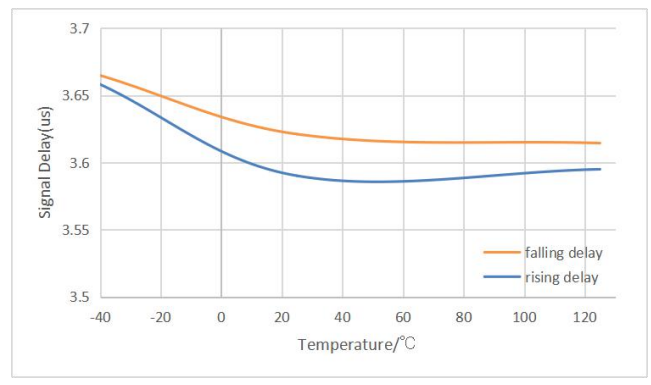


Figure 5.10 Vin to Vout Delay vs Temperature

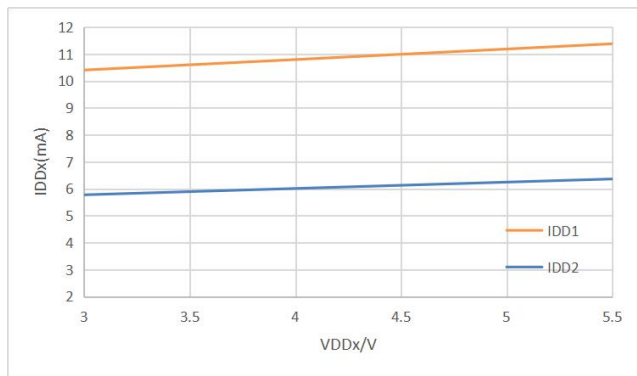


Figure 5.11 Supply Current vs Supply Voltage

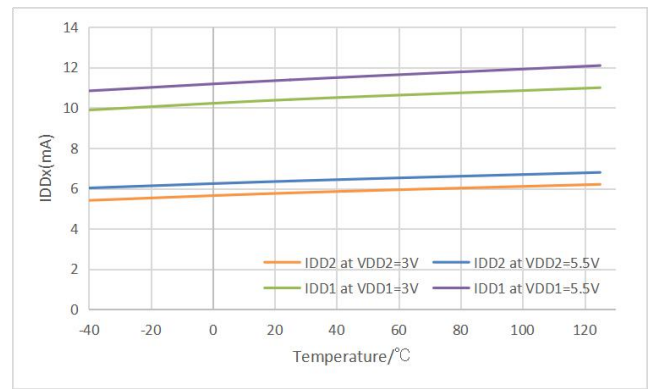


Figure 5.12 Supply Current vs Temperature

5.3. Parameter Measurement Information

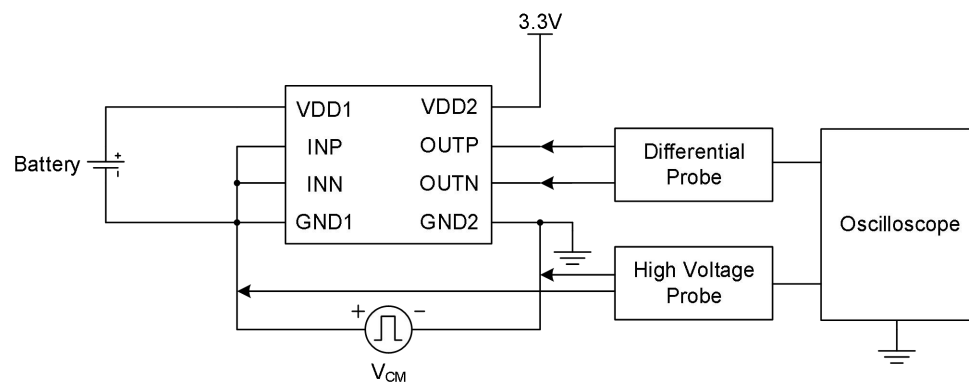


Figure 5.13 Common-Mode Transient Immunity Test Circuit

6. High Voltage Feature Description

6.1. Insulation and Safety Related Specifications

| Parameters | Symbol | Value | | Unit | Comments |
|--------------------------------------------------|--------|-------|--------------|------|-------------------------------------------------------------------|
| | | DUB8 | SOP8(300mil) | | |
| Minimum External Air Gap (Clearance) | L(I01) | ≥ 6.5 | ≥ 8 | mm | Shortest terminal-to-terminal distance through air |
| Minimum External Tracking (Creepage) | L(I02) | ≥ 6.5 | ≥ 8 | mm | Shortest terminal-to-terminal distance across the package surface |
| Minimum internal gap | DTI | 32 | 32 | μm | Distance through insulation |
| Tracking Resistance (Comparative Tracking Index) | CTI | >600 | >600 | V | DIN EN 60112 (VDE 0303-11); IEC 60112 |
| Material Group | | I | I | | IEC 60664-1 |

6.2. DIN VDE V 0884-11 (VDE V 0884-11): 2017-01 Insulation Characteristics

| Description | Test Condition | Symbol | Value | | Unit |
|-------------|----------------|--------|-------|--------------|------|
| | | | DUB8 | SOP8(300mil) | |

| Description | Test Condition | Symbol | Value | | Unit |
|-----------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------|-------------|-----------|--------------|------------------|
| | | | DUB8 | SOP8(300mil) | |
| Installation Classification per DIN VDE 0110 | | | | | |
| For Rated Mains Voltage $\leq 150\text{Vrms}$ | | | I to IV | I to IV | |
| For Rated Mains Voltage $\leq 300\text{Vrms}$ | | | I to IV | I to IV | |
| For Rated Mains Voltage $\leq 400\text{Vrms}$ | | | I to IV | I to IV | |
| Climatic Classification | | | 40/125/21 | 40/125/21 | |
| Pollution Degree per DIN VDE 0110, Table 1 | | | 2 | 2 | |
| Maximum repetitive isolation voltage | | V_{IORM} | 2121 | 2121 | V_{PEAK} |
| Maximum working isolation voltage | AC Voltage | V_{IOWM} | 1500 | 1500 | V_{RMS} |
| | DC Voltage | | 2121 | 2121 | V_{DC} |
| Input to Output Test Voltage, Method B1 | $V_{IORM} \times 1.875 = V_{pd(m)}$ 100% production test, $t_{ini} = t_m = 1 \text{ sec}$, partial discharge $< 5 \text{ pC}$ | $V_{pd(m)}$ | 2652 | 2652 | V_{PEAK} |
| Input to Output Test Voltage, Method A | | | | | |
| After Environmental Tests Subgroup 1 | $V_{IORM} \times 1.5 = V_{pd(m)}$ $t_{ini} = 60 \text{ sec}$, $t_m = 10 \text{ sec}$, partial discharge $< 5 \text{ pC}$ | $V_{pd(m)}$ | 2121 | 2121 | V_{PEAK} |
| After Input and /or Safety Test Subgroup 2 and Subgroup 3 | $V_{IORM} \times 1.2 = V_{pd(m)}$, $t_{ini} = 60 \text{ sec}$, $t_m = 10 \text{ sec}$, partial discharge $< 5 \text{ pC}$ | $V_{pd(m)}$ | 1697 | 1697 | V_{PEAK} |
| Maximum transient isolation voltage | $t = 60 \text{ sec}$ | V_{IOTM} | 8000 | 8000 | V_{PEAK} |
| Maximum Surge Isolation Voltage | Test method per IEC60065, 1.2/50us waveform, $V_{TEST} = V_{IOSM}/1.6$ | V_{IOSM} | 6250 | 6250 | V_{PEAK} |
| Isolation resistance | $V_{IO} = 500\text{V}$ | R_{IO} | $>10^9$ | $>10^9$ | Ω |
| Isolation capacitance | $f = 1\text{MHz}$ | C_{IO} | 0.8 | 0.8 | pF |
| Input capacitance | | C_I | 2 | 2 | pF |
| Total Power Dissipation at 25 °C | | P_s | 1650 | 1430 | mW |
| Safety input, output, or supply current | $\theta_{JA} = 75 \text{ }^\circ\text{C/W}$, $V_I = 5.5\text{V}$, $T_J = 150 \text{ }^\circ\text{C}$, $T_A = 25 \text{ }^\circ\text{C}$ | I_s | 300 | | mA |
| Safety input, output, or supply current | $\theta_{JA} = 86 \text{ }^\circ\text{C/W}$, $V_I = 5.5\text{V}$, $T_J = 150 \text{ }^\circ\text{C}$, $T_A = 25 \text{ }^\circ\text{C}$ | I_s | | 260 | mA |
| Maximum safety temperature | | T_s | 150 | 150 | $^\circ\text{C}$ |

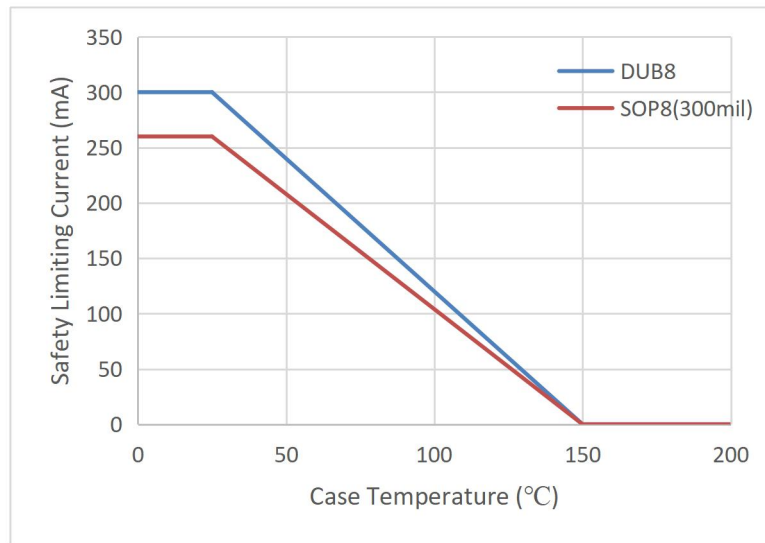


Figure 6.1 NSi1200 Thermal Derating Curve, Dependence of Safety Limiting Values with Case Temperature per DIN VDE V 0884-11

6.3. Regulatory Information

The NSi1200 are approved or pending approval by the organizations listed in table.

| UL | | VDE | CQC |
|-----------------------------------------------------------|-----------------------------------------------------------|-----------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------|
| UL 1577 Component Recognition Program | Approved under CSA Component Acceptance Notice 5A | DIN VDE V 0884-11(VDE V 0884-11):2017-01 | Certified by CQC11-471543-2012 GB4943.1-2011 |
| Single Protection, 5000V _{rms} Isolation voltage | Single Protection, 5000V _{rms} Isolation voltage | Reinforce Insulation 1414Vpeak, V _{IOSM} =6250Vpeak | Basic insulation at 1000V _{RMS} (1414Vpeak) Reinforced insulation at 400V _{RMS} (565Vpeak) |
| File (pending) | File (pending) | File (pending) | File (pending) |

7. Function Description

7.1. Overview

The NSi1200 is a fully-differential, precision, isolated amplifier. The input stage of the device consists of a fully-differential amplifier that drives a second-order, sigma-delta ($\Sigma\Delta$) modulator. The modulator uses the internal voltage reference and clock generator to convert the analog input signal to a digital bitstream. The drivers (called TX in the Functional Block Diagram) transfer the output of the modulator across the isolation barrier that separates the side1 and side2 voltage domains. The received bitstream and clock are synchronized and processed, as shown in the Functional Block Diagram, by a fourth-order analog filter on the side2 and presented as a differential output of the device.

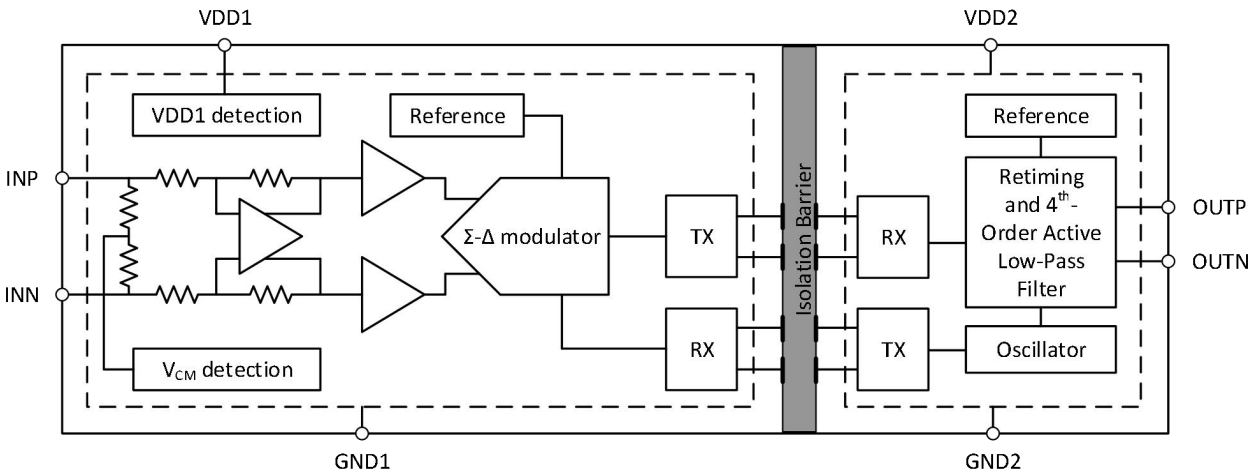


Figure 7.1 Function Block Diagram

7.2. Analog Input

There are two restrictions on the analog input signals (VINP and VINN).

- If the input voltage exceeds the range $GND1 - 6V$ to $VDD1 + 0.5V$, the input current must be limited to 10 mA because the device input electrostatic discharge (ESD) diodes turn on.
- The linearity and noise performance of the device are ensured only when the analog input voltage remains within the specified linear full-scale range (FSR) and within the specified common-mode input voltage range.

7.3. Analog Output

For linear input range, the analog output of NSI1200 has a fixed gain of 8. If a full-scale input signal is applied to the NSI1200 ($V_{IN} \geq V_{Clipping}$), the analog output will be clipped (typically, 2.4V for positive clipping and -2.4V for negative clipping).

In addition, NSI1200 integrates some diagnostic measures and offers a fail-safe output to simplify system-level design. The fail-safe output is a negative differential output voltage that does not occur under normal device operation, and it will only be activated in following conditions:

- When the undervoltage of VDD1 is detected ($VDD1 < VDD1_{UV}$).
- When the overvoltage of common-mode input voltage is detected ($V_{CM} > V_{CMov}$).

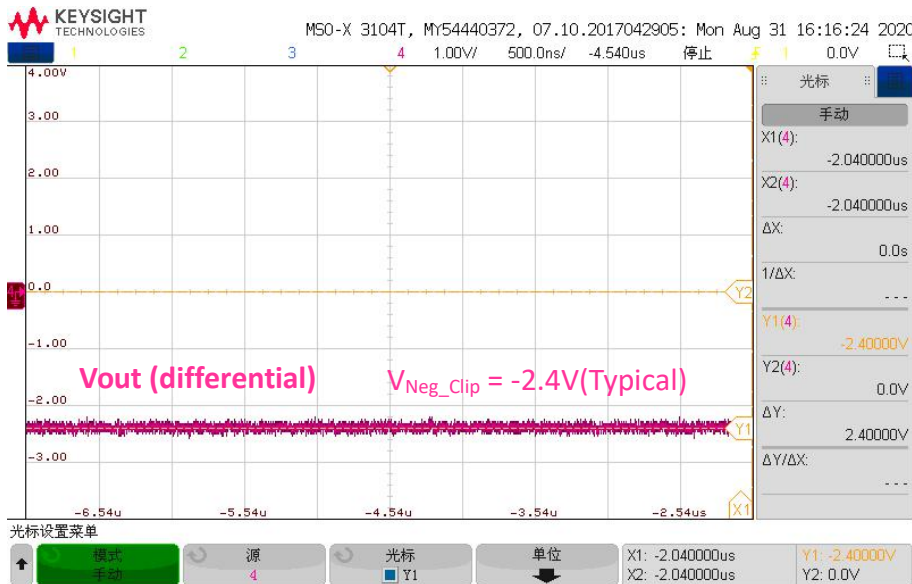


Figure 7.2 Typical negative clipping output

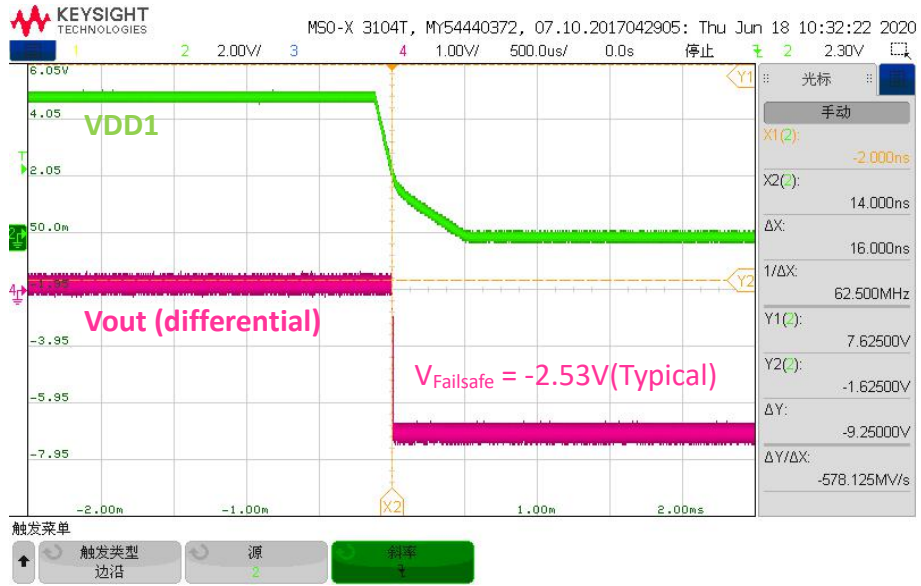


Figure 7.3 Typical Failsafe output when VDD1 undervoltage

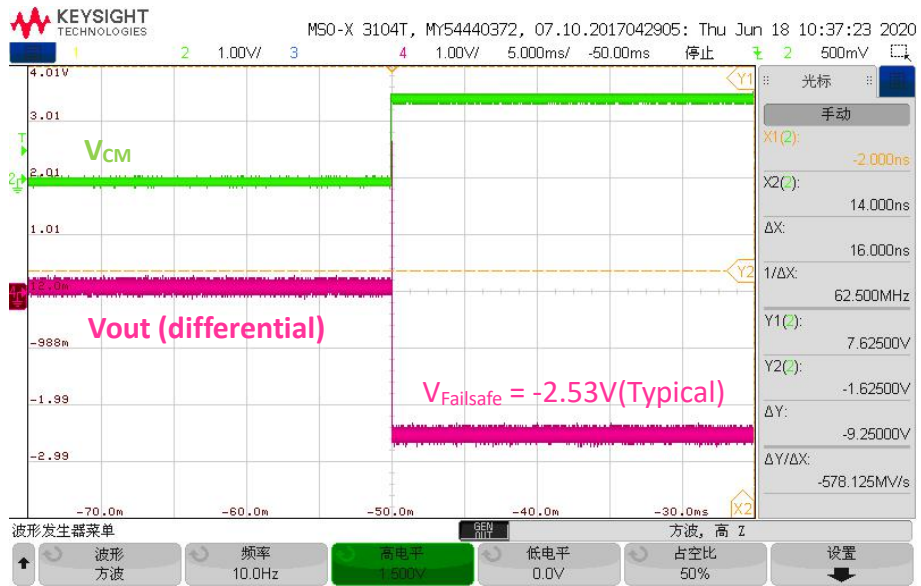


Figure 7.4 Typical Failsafe output when input common mode signal overvoltage

8. Application Note

8.1. Typical Application Circuit

NSi1200 is ideally suited to shunt resistor-based current sensing in high voltage applications such as frequency inverters. The typical application circuit is shown in Figure 8.1.

The voltage across the shunt resistor R_{sense} is applied to the differential input of NSi1200 through a RC filter. The differential output of the isolated amplifier is converted to a single-ended analog output with an operational-amplifier-based circuit. Suggest to add $>1k\Omega$ resistor on the OUPN and OUPN pin to prevent output over-current. An analog-to-digital converter usually receives the analog output and converts to digital signal for controller processing.

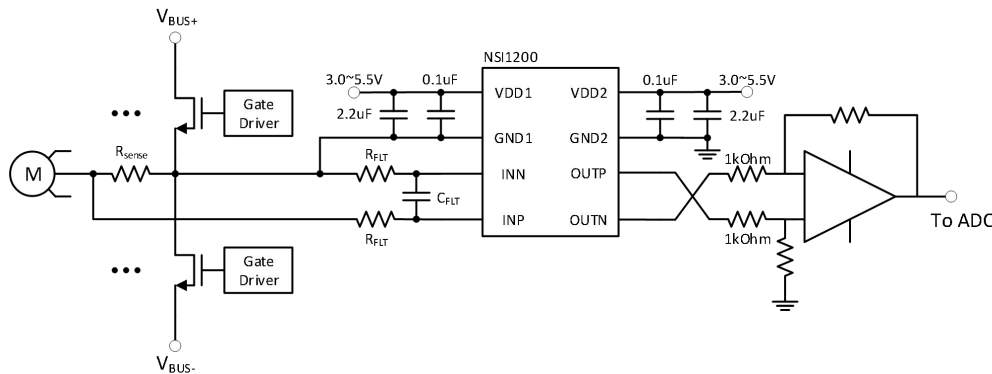


Figure 8.1 Typical application circuit in phase current sensing

8.2. Shunt Resistor Selection

Choosing a particular shunt resistor is usually a compromise between minimizing power dissipation and maximizing accuracy. Smaller sense resistor decreases power dissipation, while larger sense resistor can improve measure accuracy by utilizing the full input range of isolated amplifier.

There are two other factors should be considered when selecting the shunt resistor:

- The voltage-drop caused by the rated current range must not exceed the recommended linear input voltage range: $V_{SHUNT} \leq FSR$.
- The voltage-drop caused by the maximum allowed overcurrent must not exceed the input voltage that causes a clipping output: $V_{SHUNT} \leq V_{Clipping}$.

8.3. PCB Layout

There are some key guidelines or considerations for optimizing performance in PCB layout:

- NSi1200 requires a $0.1\mu F$ bypass capacitor between VDD1 and GND1, VDD2 and GND2. The capacitor should be placed as close as possible to the VDD pin. If better filtering is required, an additional $1\sim 10\mu F$ capacitor may be used.
- Kelvin rules is recommended for the connection between shunt resistor to NSi1200. Because of the Kelvin connection, any voltage drops across the trace and leads should have no impact on the measured voltage.
- Place the shunt resistor close to the INP and INN inputs and keep the layout of both connections symmetrical and run very close to each other to the input of the NSi1200. This minimizes the loop area of the connection and reduces the possibility of stray magnetic fields from interfering with the measured signal.

9. Package Information

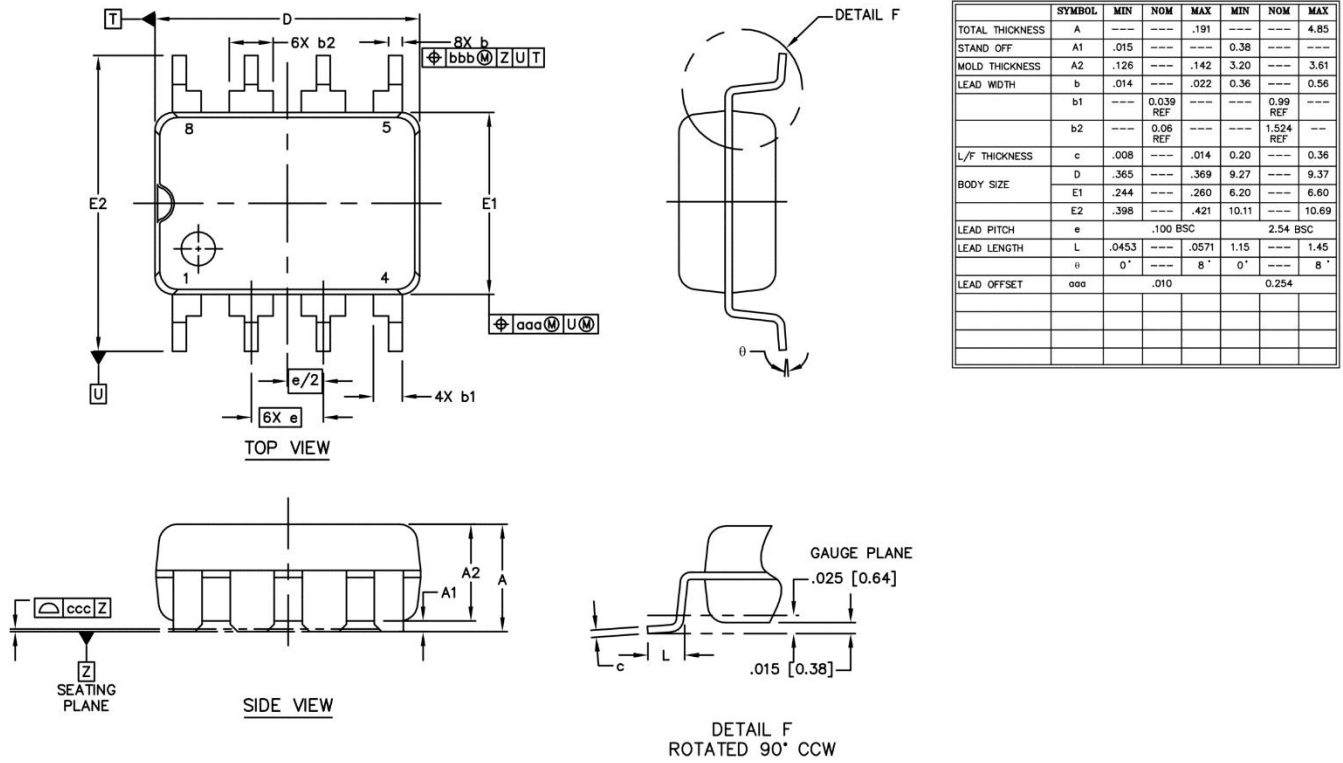


Figure 9.1 DUB8 Package Shape and Dimension in millimeters

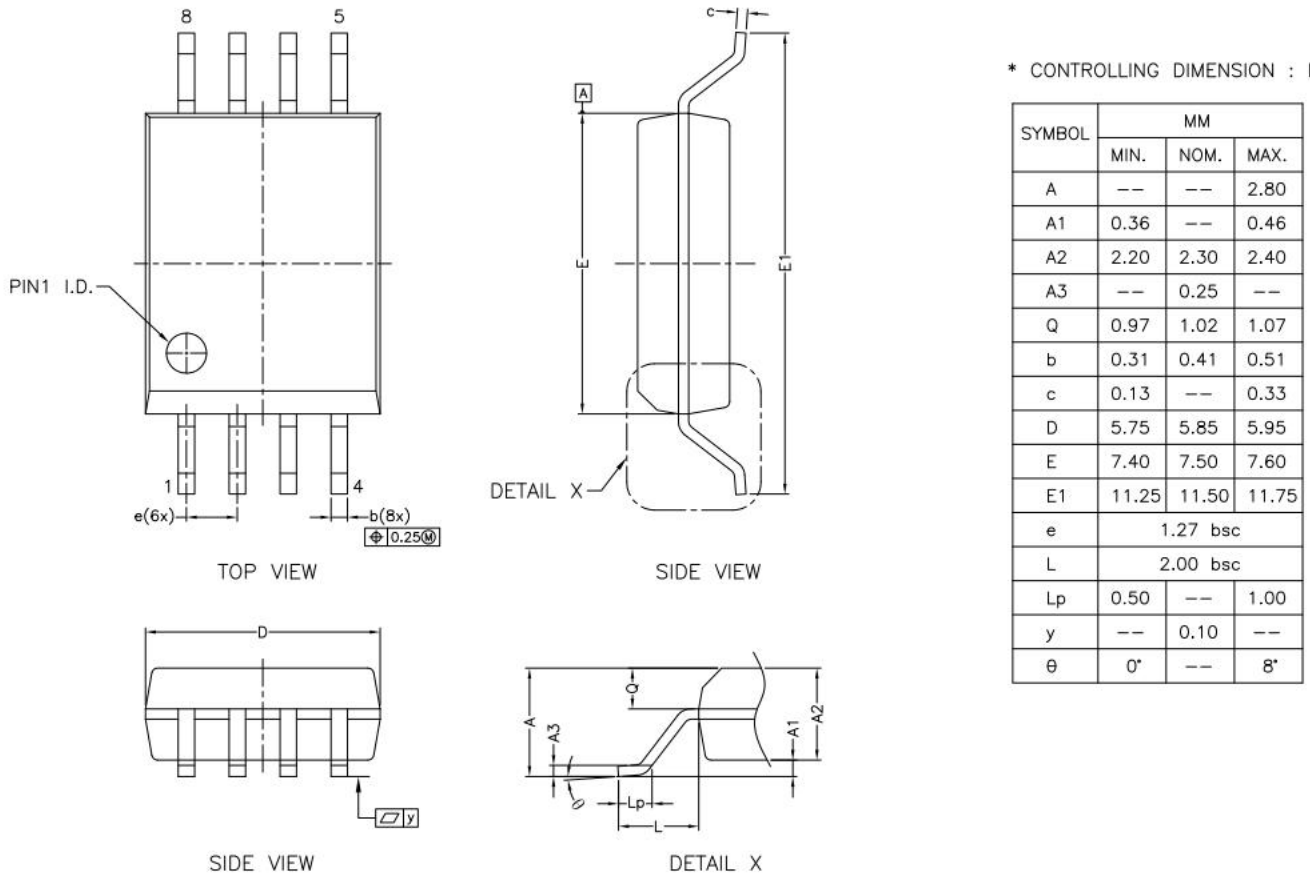


Figure 9.2 SOW8 Package Shape and Dimension in millimeters

10. Ordering Information

| Part No. | Isolation Rating(kV) | Linear Input Range(mV) | Moisture Sensitivity Level | Temperature | Automotive | Package Type | Package Drawing | SPQ |
|-----------------|----------------------|------------------------|----------------------------|--------------|------------|---------------|-----------------|------|
| NSi1200 - DSWVR | 5 | -250 ~ 250 | Level-3 | -40 to 125°C | NO | SOP8 (300mil) | SOW8 | 1000 |
| NSi1200- DDBR | 5 | -250 ~ 250 | Level-3 | -40 to 125°C | NO | DUB8 | DUB8 | 800 |

11. Documentation Support

| Part Number | Product Folder | Datasheet | Technical Documents | Isolator selection guide |
|-------------|----------------------------|----------------------------|----------------------------|----------------------------|
| NSi1200 | Click here | Click here | Click here | Click here |

12. Tape and Reel Information

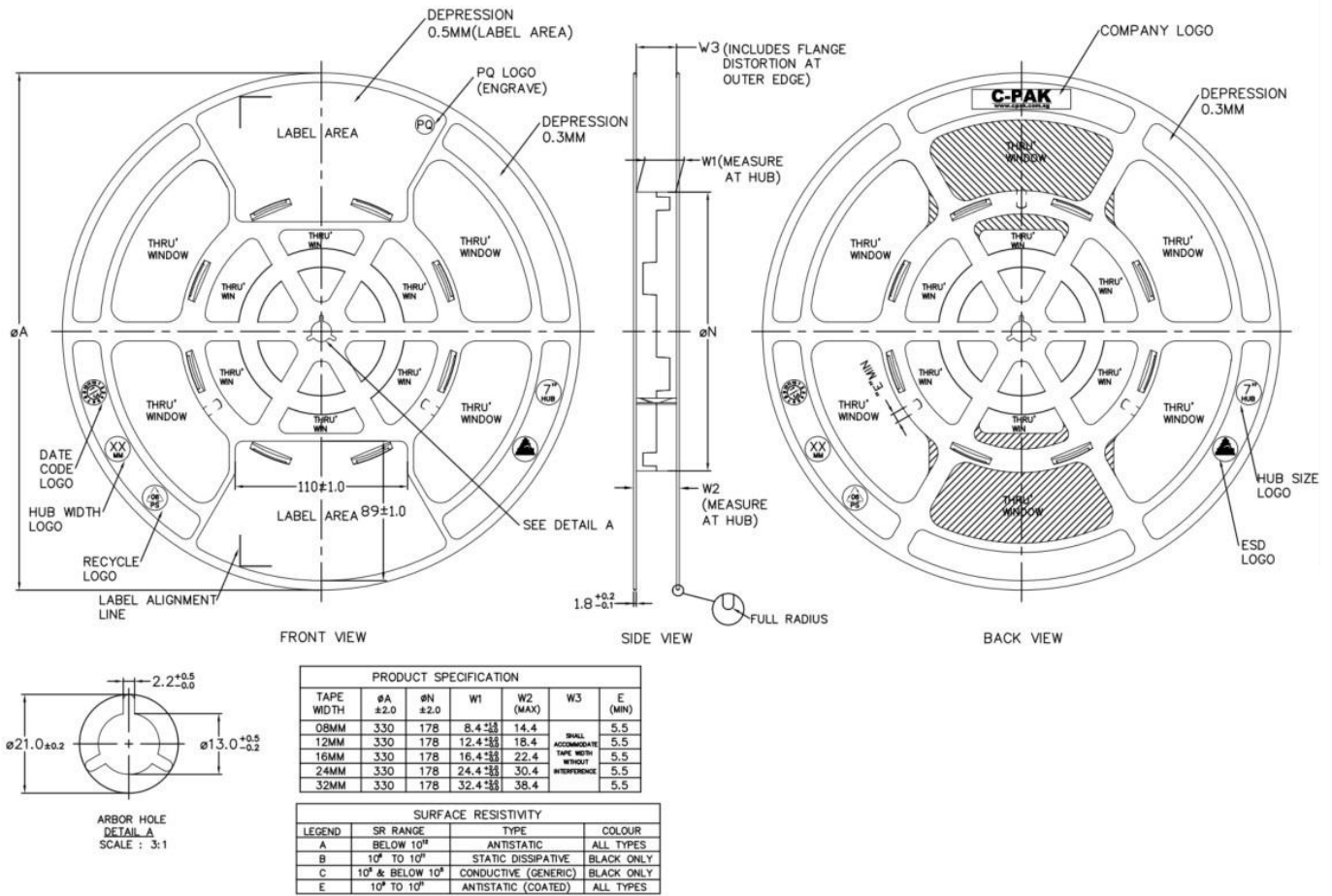


Figure 12.1 Tape Information

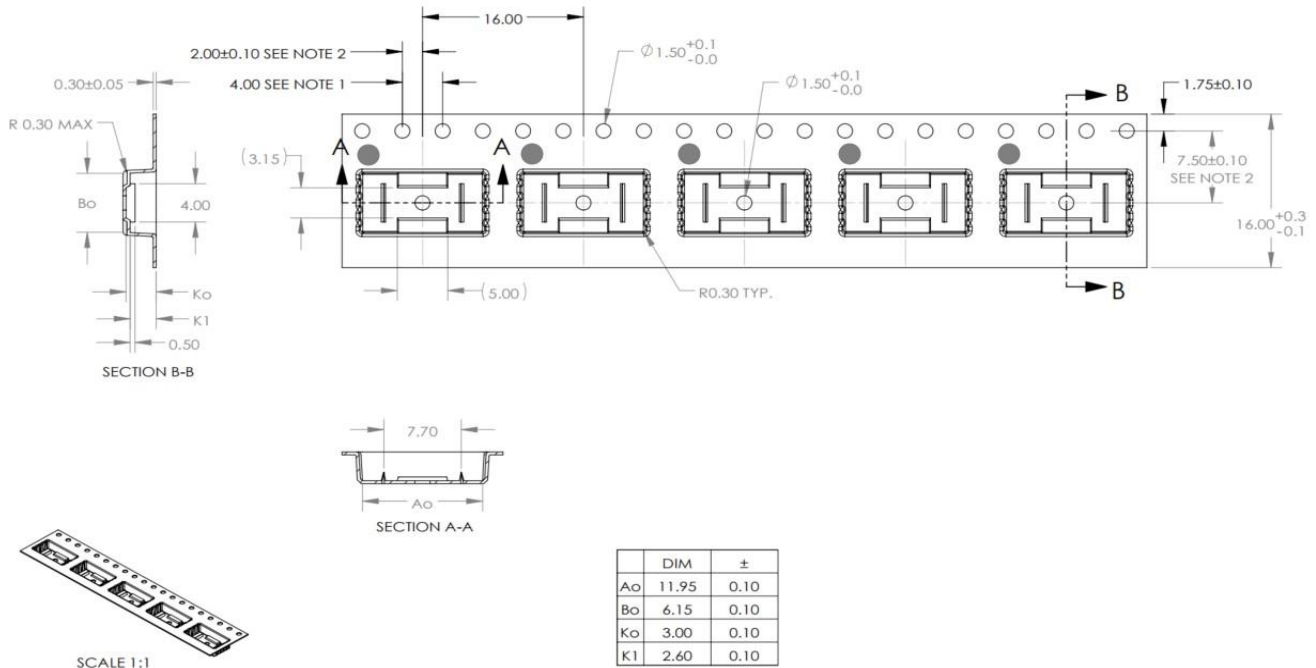


Figure 12.2 Reel Information of SOP8(300mil)

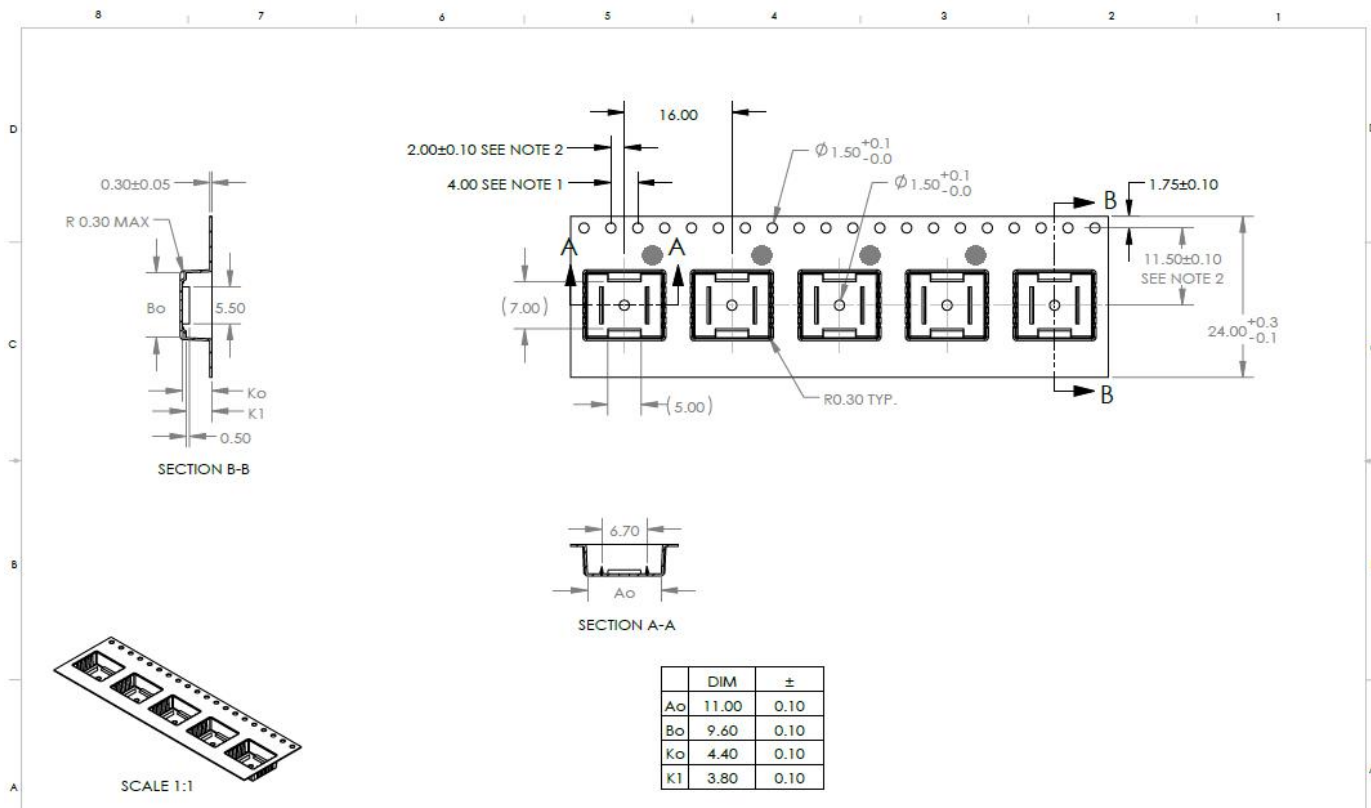


Figure 12.3 Reel Information of DUB8

13. Revision History

| Revision | Description | Date |
|----------|-----------------|-----------|
| 1.0 | Initial Release | 2021/1/11 |

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